NSN 5961-01-373-7052

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-373-7052 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** 1.100 millimeters **Overall Width:** Between 1.2 millimeters and 1.4 millimeters **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 25.00 milliamperes all primaries **Power Rating Per Characteristic:** 300.00 milliwatts any acceptable preset **Transfer Ratio:** 90.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No